

Small Signal MOSFET 115 mAmps, 60 Volts N-Channel

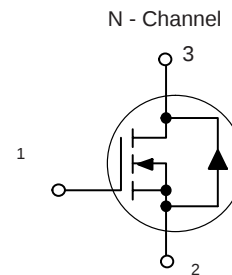
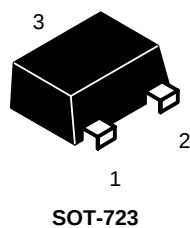
FEATURES:

- We declare that the material of product compliance with RoHS requirements and Halogen Free.

APPLICATIONS:

- Load Switch

Circuit Diagram & Pin Configuration:



DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
2N7002M3-S08T	72	8000/Tape&Reel

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	60	Vdc
Drain-Gate Voltage ($R_{GS} = 1.0 \text{ M}\Omega$)	V_{DGR}	60	Vdc
Drain Current	I_D	± 115	mAdc
– Continuous $T_C = 25^\circ\text{C}$ (Note 1.)	I_{DM}	± 800	
– Pulse $t < 10\mu\text{s}$			
Gate-Source Voltage	V_{GS}	± 20	Vdc
– Continuous			

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 2.) $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	150 1.2	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	833	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to $+150$	$^\circ\text{C}$

1. The Power Dissipation of the package may result in a lower continuous drain current.
2. FR-5 = $1.0 \times 0.75 \times 0.062$ in.
3. Alumina = $0.4 \times 0.3 \times 0.025$ in 99.5% alumina.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Drain-Source Breakdown Voltage ($V_{GS} = 0$, $I_D = 10\ \mu\text{Adc}$)	$V_{(BR)DSS}$	60	—	—	Vdc
Zero Gate Voltage Drain Current ($V_{GS} = 0$, $V_{DS} = 60\ \text{Vdc}$)	I_{DSS}	— —	— —	1.0 500	μAdc
Gate-Body Leakage Current, Forward ($V_{GS} = 20\ \text{Vdc}$)	I_{GSSF}	—	—	100	nAdc
Gate-Body Leakage Current, Reverse ($V_{GS} = -20\ \text{Vdc}$)	I_{GSSR}	—	—	-100	nAdc

ON CHARACTERISTICS (Note 2.)

Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 250\ \mu\text{Adc}$)	$V_{GS(th)}$	1.0	1.8	2.2	Vdc
On-State Drain Current ($V_{DS} \geq 2.0\ V_{DS(on)}$, $V_{GS} = 10\ \text{Vdc}$)	$I_{D(on)}$	500	—	—	mA
Static Drain-Source On-State Voltage ($V_{GS} = 10\ \text{Vdc}$, $I_D = 500\ \text{mAdc}$) ($V_{GS} = 5.0\ \text{Vdc}$, $I_D = 50\ \text{mAdc}$)	$V_{DS(on)}$	— —	— —	3.75 0.375	Vdc
Static Drain-Source On-State Resistance ($V_{GS} = 10\ \text{V}$, $I_D = 500\ \text{mAdc}$) ($V_{GS} = 5.0\ \text{Vdc}$, $I_D = 50\ \text{mAdc}$)	$r_{DS(on)}$	— —	— —	4 4	Ohms
Forward Transconductance ($V_{DS} \geq 2.0\ V_{DS(on)}$, $I_D = 200\ \text{mAdc}$)	g_{FS}	80	—	—	mmhos

DYNAMIC CHARACTERISTICS

Input Capacitance ($V_{DS} = 25\ \text{Vdc}$, $V_{GS} = 0$, $f = 1.0\ \text{MHz}$)	C_{iss}	—	17	50	pF
Output Capacitance ($V_{DS} = 25\ \text{Vdc}$, $V_{GS} = 0$, $f = 1.0\ \text{MHz}$)	C_{oss}	—	10	25	pF
Reverse Transfer Capacitance ($V_{DS} = 25\ \text{Vdc}$, $V_{GS} = 0$, $f = 1.0\ \text{MHz}$)	C_{rss}	—	2.5	5.0	pF

SWITCHING CHARACTERISTICS (Note 2.)

Turn-On Delay Time	(V _{DD} = 25 Vdc, I _D = 500 mAdc, R _G = 25 Ω , R _L = 50 Ω , V _{gen} = 10 V)	t _{d(on)}	—	7	20	ns
Turn-Off Delay Time		t _{d(off)}	—	11	40	ns

BODY-DRAIN DIODE RATINGS

Diode Forward On-Voltage (I _S = 115 mAdc, V _{GS} = 0 V)	V_{SD}	—	—	-1.5	Vdc
Source Current Continuous (Body Diode)	I_S	—	—	-115	mAdc
Source Current Pulsed	I_{SM}	—	—	-800	mAdc

2. Pulse Test: Pulse Width $\leq 300\ \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

TYPICAL ELECTRICAL CHARACTERISTICS

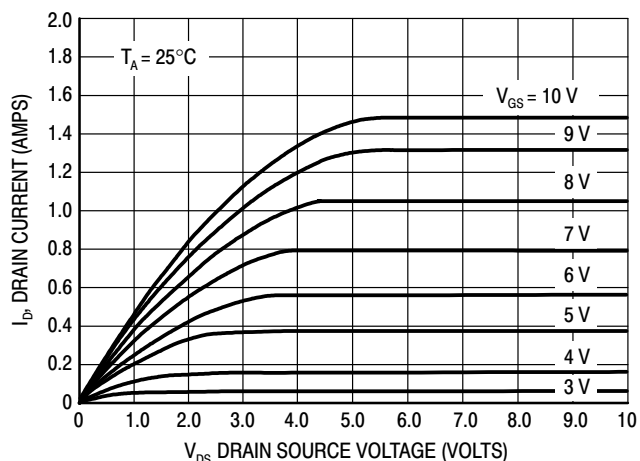


Figure 1. Ohmic Region

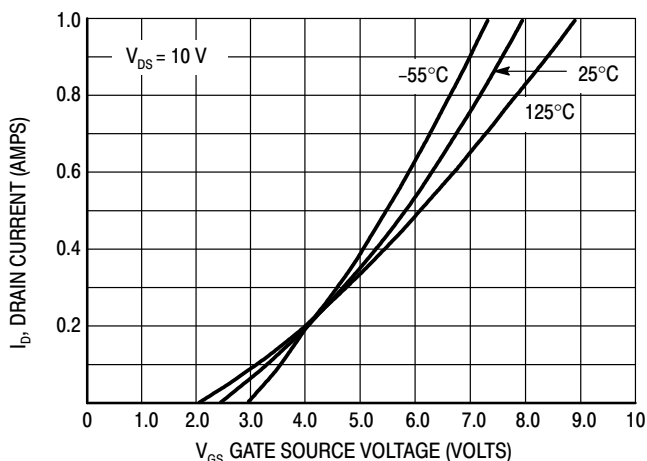


Figure 2. Transfer Characteristics

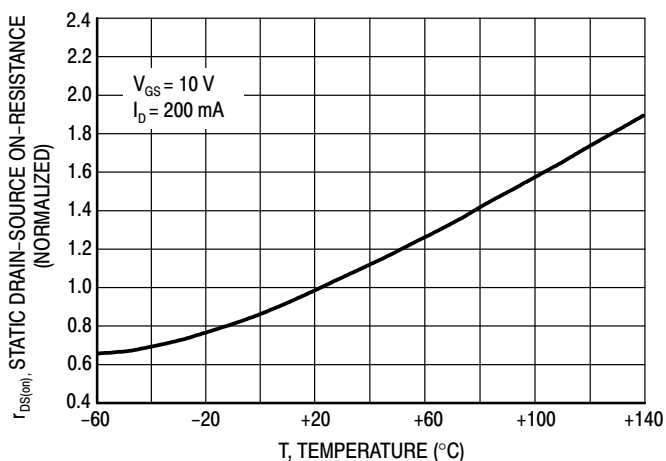


Figure 3. Temperature versus Static Drain-Source On-Resistance

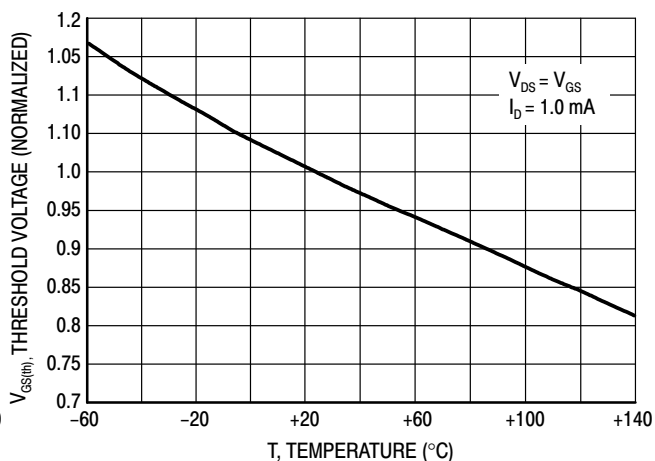
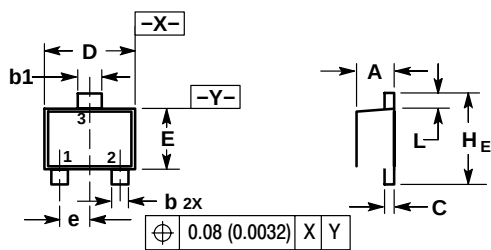


Figure 4. Temperature versus Gate Threshold Voltage

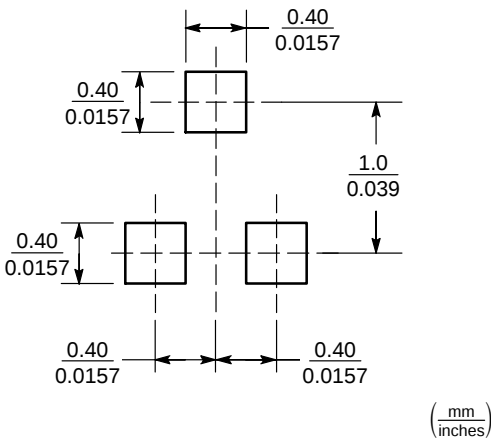
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- NOTES:
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 - 2. CONTROLLING DIMENSION: MILLIMETERS.
 - 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 - 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
b	0.15	0.20	0.27	0.0059	0.0079	0.0106
b1	0.25	0.3	0.35	0.010	0.012	0.014
C	0.07	0.12	0.17	0.0028	0.0047	0.0067
D	1.15	1.20	1.25	0.045	0.047	0.049
E	0.75	0.80	0.85	0.03	0.032	0.034
e	0.40 BSC			0.016 BSC		
H	1.15	1.20	1.25	0.045	0.047	0.049
L	0.15	0.20	0.25	0.0059	0.0079	0.0098

SOLDERING FOOTPRINT



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